# NSN 5961-01-077-5440

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## Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

# **Overall Width:**

1.050 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

850.0 collector to emitter voltage, dc with specified circuit between base and emitter and 400.0 collector to emitter voltage/static/base open

and 8.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 15.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

175.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### Terminal Type And Quantity:

1 case and 2 pin

#### **Specification Data:**

81349-mil-s-19500/525 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

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